

RJH60F5BDPQ-A0

600V - 40A - IGBT
High Speed Power Switching

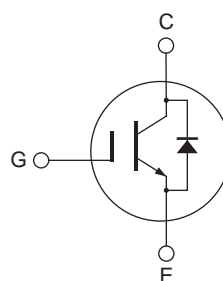
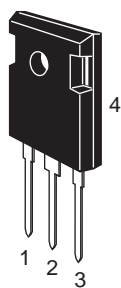
R07DS0631EJ0100
Rev.1.00
Feb 17, 2012

Features

- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 1.37 \text{ V typ. (} I_C = 40 \text{ A, } V_{GE} = 15 \text{ V, } T_a = 25^\circ\text{C)}$
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching
 $t_f = 68 \text{ ns typ. (at } I_C = 30 \text{ A, } V_{CE} = 400 \text{ V, } V_{GE} = 15 \text{ V, } R_g = 5 \Omega, T_a = 25^\circ\text{C, inductive load)}$

Outline

RENESAS Package code: PRSS0003ZH-A
(Package name: TO-247A)



1. Gate
2. Collector
3. Emitter
4. Collector

Absolute Maximum Ratings

($T_c = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Collector to emitter voltage	V_{CES}	600	V
Gate to emitter voltage	V_{GES}	± 30	V
Collector current	$T_c = 25^\circ\text{C}$	I_C	80
	$T_c = 100^\circ\text{C}$	I_C	40
Collector peak current	$i_{c(peak)}$ ^{Note1}	160	A
Collector to emitter diode forward peak current	$i_{DF(peak)}$ ^{Note2}	100	A
Collector dissipation	P_C	260.4	W
Junction to case thermal impedance (IGBT)	θ_{j-c}	0.48	$^\circ\text{C/W}$
Junction to case thermal impedance (Diode)	θ_{j-cd}	1.1	$^\circ\text{C/W}$
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. Pulse width limited by safe operating area.

2. $PW \leq 5 \mu\text{s}$, duty cycle $\leq 1\%$

Electrical Characteristics

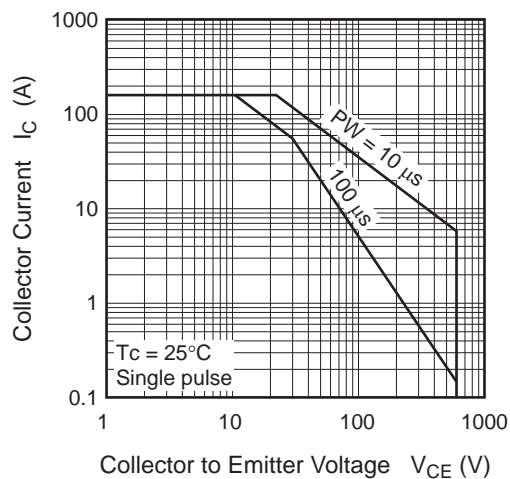
(Tj = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current	I_{CES}	—	—	100	μA	$V_{CE} = 600V, V_{GE} = 0$
Gate to emitter leak current	I_{GES}	—	—	± 1	μA	$V_{GE} = \pm 30V, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4	—	8	V	$V_{CE} = 10V, I_C = 1mA$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	1.37	1.8	V	$I_C = 40A, V_{GE} = 15V$ ^{Note3}
	$V_{CE(sat)}$	—	1.7	—	V	$I_C = 80A, V_{GE} = 15V$ ^{Note3}
Input capacitance	C_{ies}	—	2780	—	pF	$V_{CE} = 25V$
Output capacitance	C_{oes}	—	122	—	pF	$V_{GE} = 0V$
Reverse transfer capacitance	C_{res}	—	43	—	pF	$f = 1MHz$
Switching time	$t_{d(on)}$	—	53	—	ns	$I_C = 30A,$ $V_{CE} = 400V, V_{GE} = 15V$ $R_g = 5\Omega$ ^{Note3} , Inductive load
	t_r	—	34	—	ns	
	$t_{d(off)}$	—	95	—	ns	
	t_f	—	68	—	ns	
C-E diode forward voltage	V_{ECF}	—	2.5	3.0	V	$I_F = 30A$ ^{Note3}
C-E diode reverse recovery time	t_{rr}	—	25	—	ns	$I_F = 30A$ $di_F/dt = 100A/\mu s$

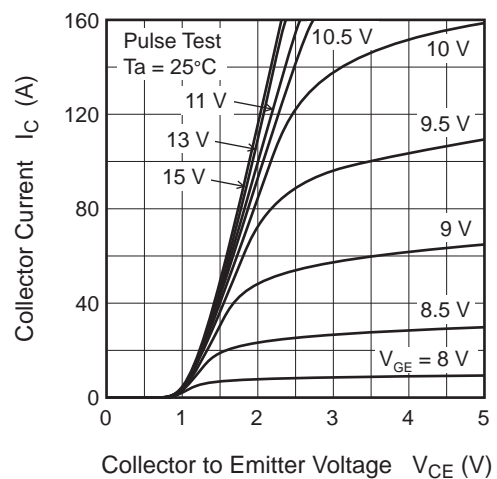
Notes: 3. Pulse test

Main Characteristics

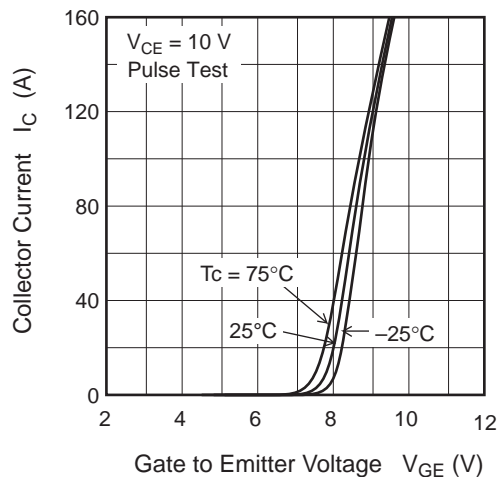
Maximum Safe Operation Area



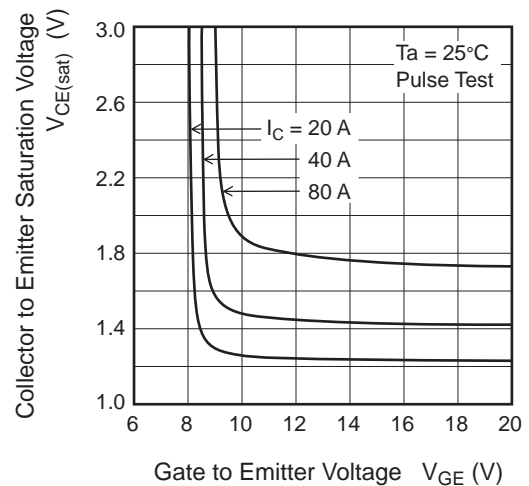
Typical Output Characteristics



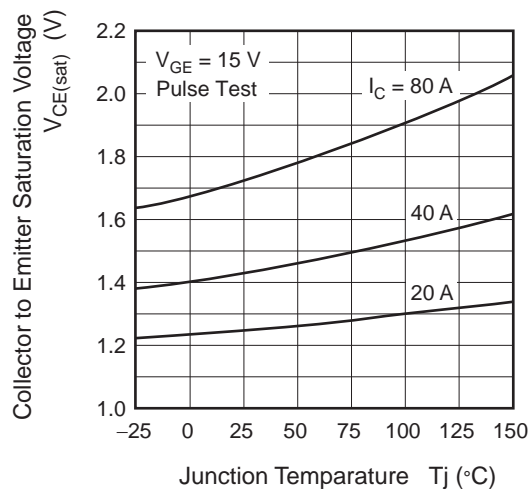
Typical Transfer Characteristics



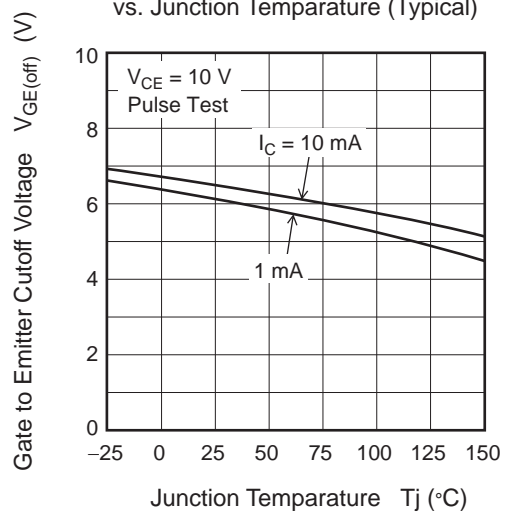
Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage (Typical)



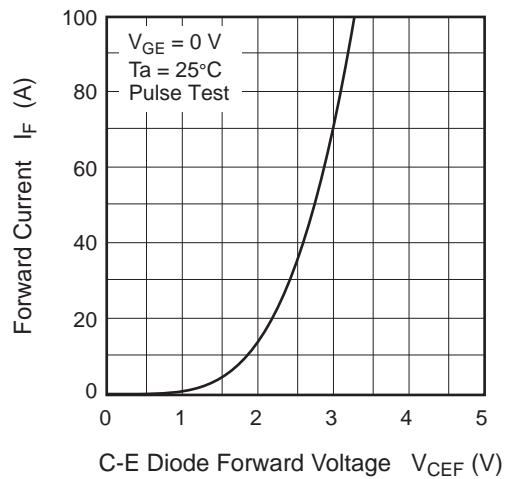
Collector to Emitter Saturation Voltage vs. Junction Temperature (Typical)



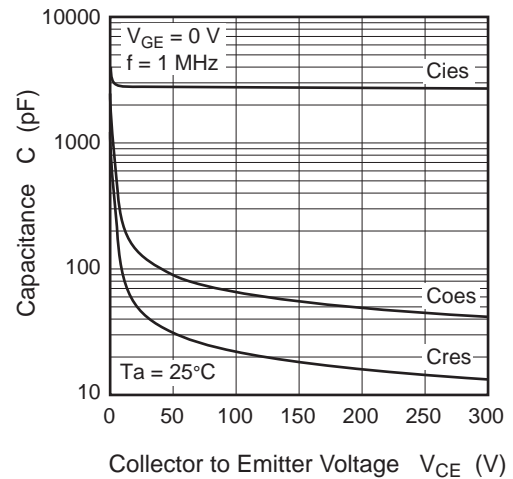
Gate to Emitter Cutoff Voltage vs. Junction Temperature (Typical)



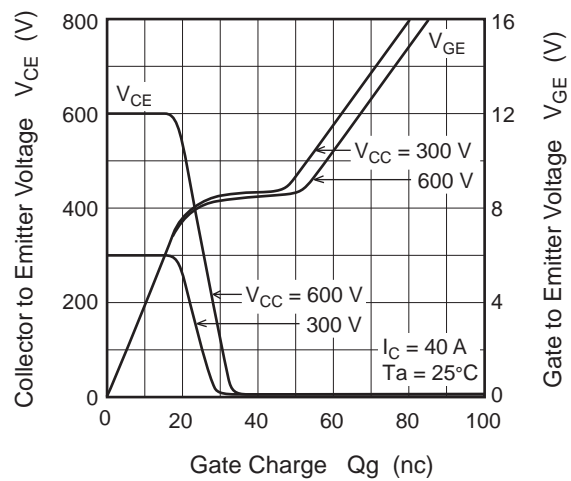
Forward Current vs. Forward Voltage (Typical)



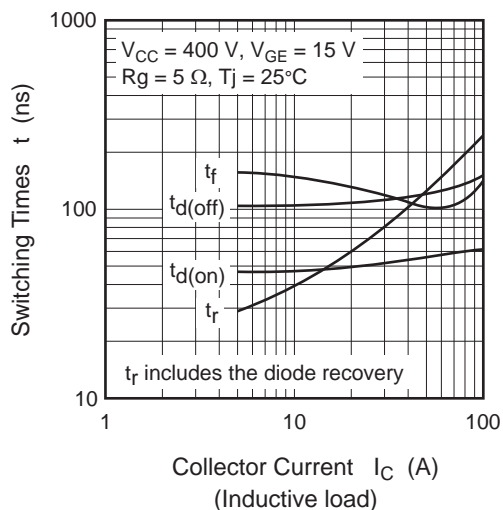
Typical Capacitance vs. Collector to Emitter Voltage



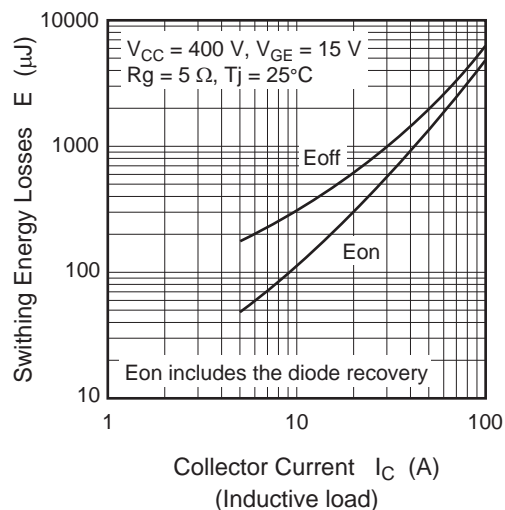
Dynamic Input Characteristics (Typical)



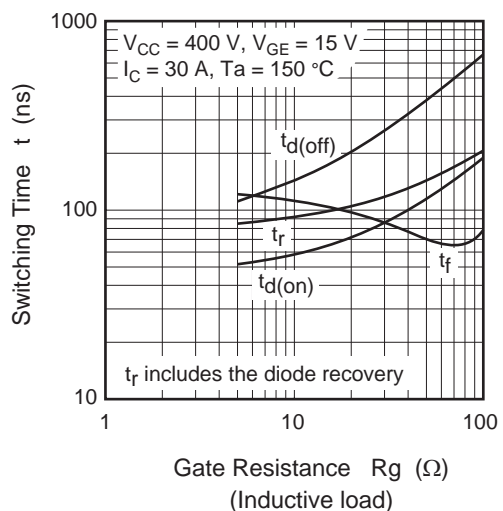
Switching Characteristics (Typical) (1)



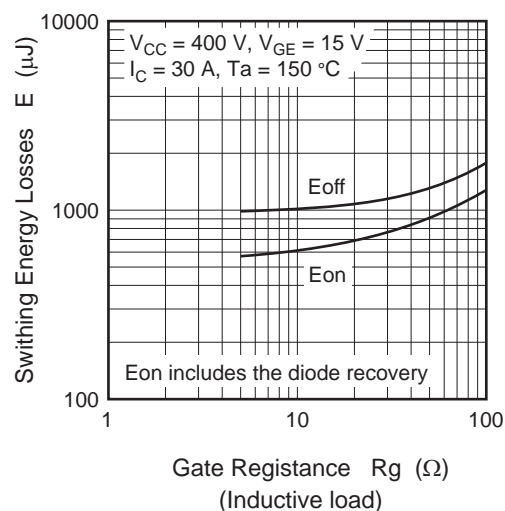
Switching Characteristics (Typical) (2)



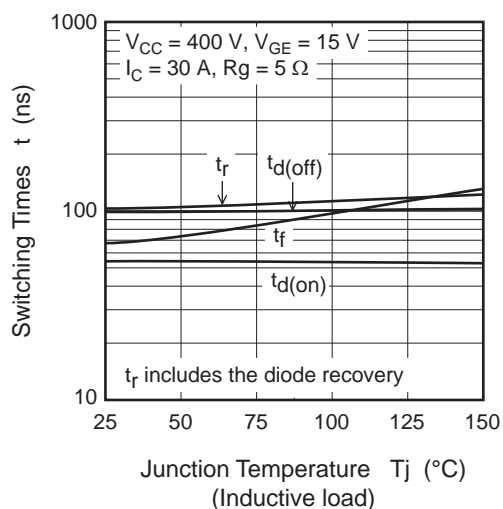
Switching Characteristics (Typical) (3)



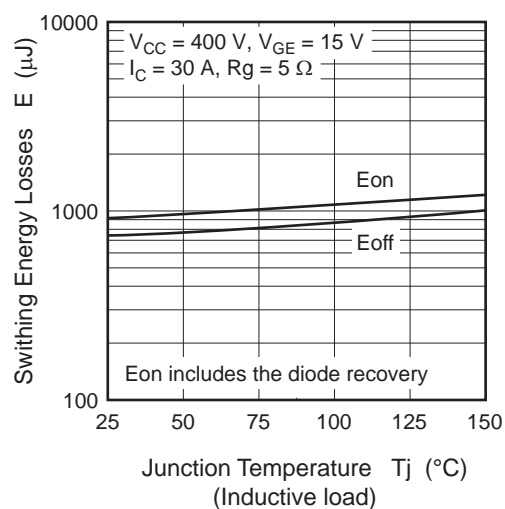
Switching Characteristics (Typical) (4)

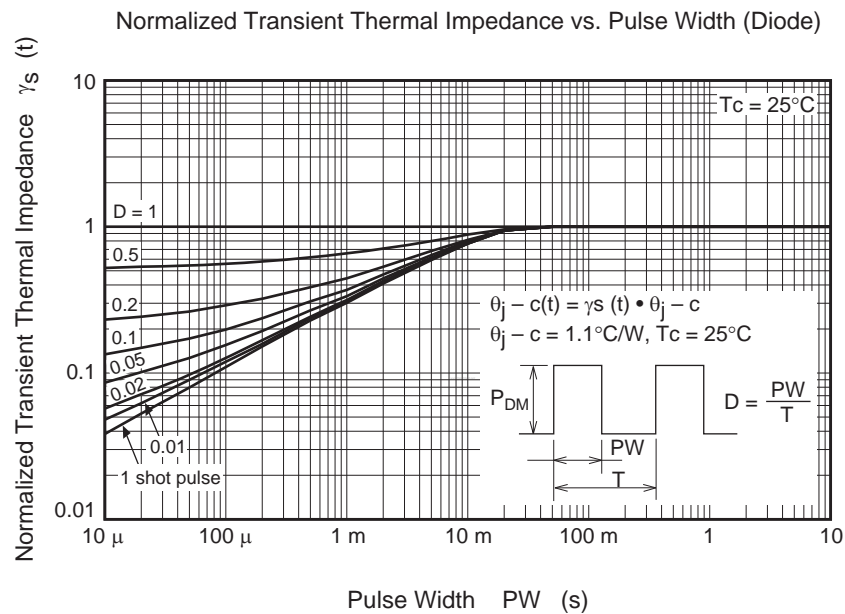
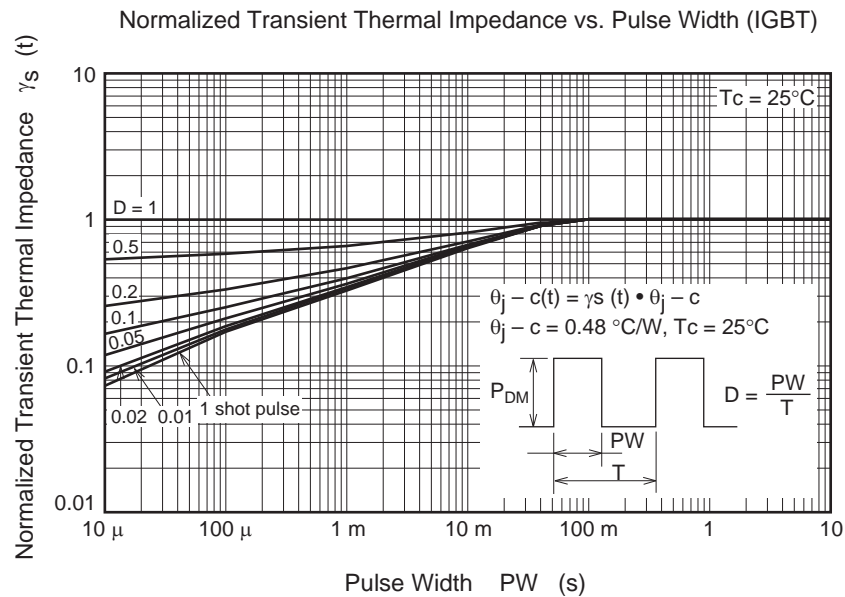


Switching Characteristics (Typical) (5)

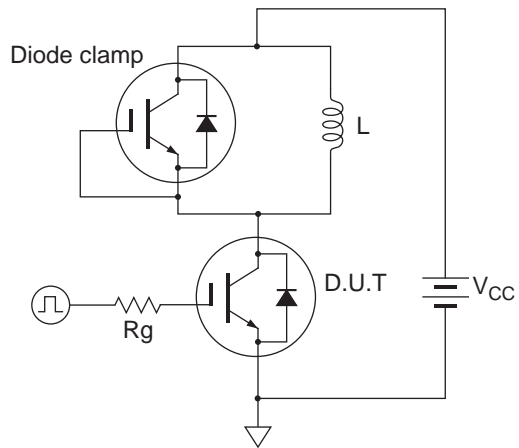


Switching Characteristics (Typical) (6)

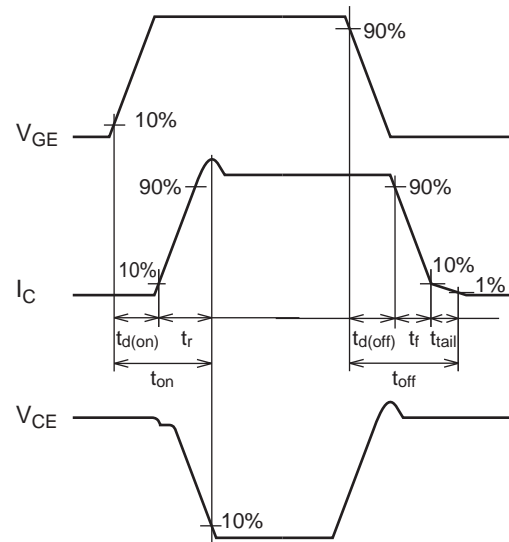




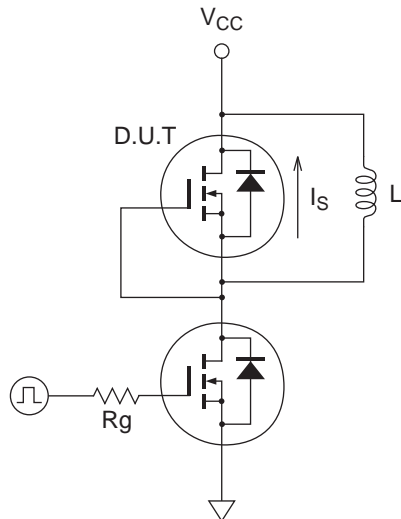
Switching Time Test Circuit



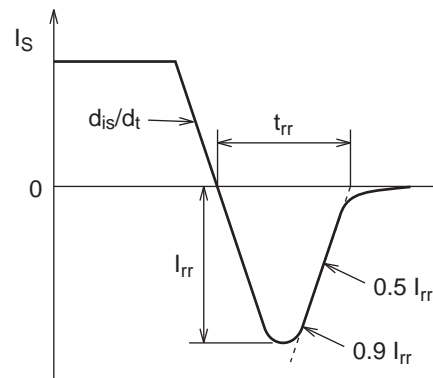
Waveform



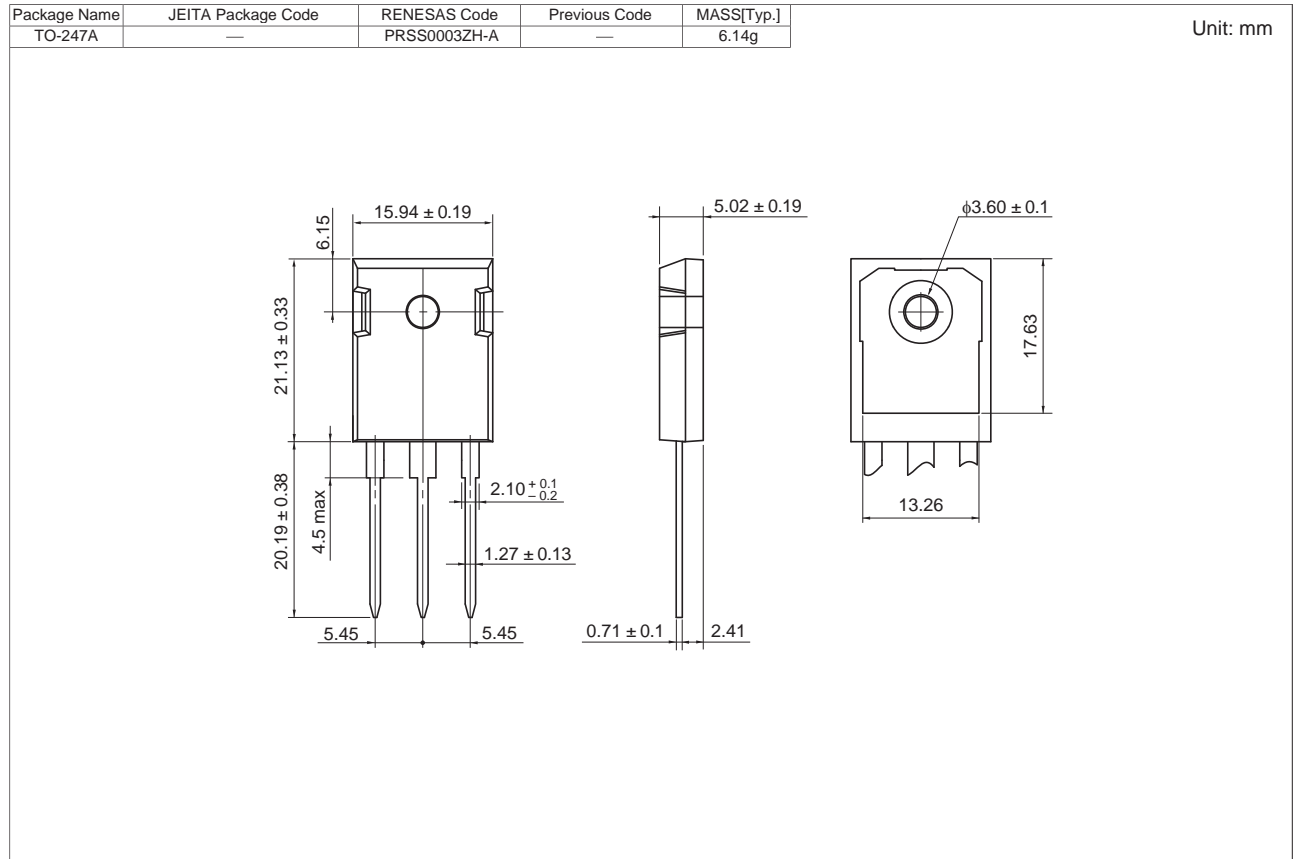
Diode Reverse Recovery Time Test Circuit



Waveform



Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60F5BDPQ-A0#T0	240 pcs	Box (Tube)

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